

<u> UF2001 - UF2007</u>

Features

- Diffused Junction
- Ultra-Fast Switching for High Efficiency
- Surge Overload Rating to 60A Peak
- Low Reverse Leakage Current
- Lead Free Finish, RoHS Compliant (Note 4)

2.60

All Dimensions in mm

3.60

DO-15 Dim Min Max 25.40 Α В 5.50 7.62 С 0.686 0.889

Mechanical Data

Case: DO-15

Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0

Moisture Sensitivity: Level 1 per J-STD-020D

Terminals: Finish - Tin. Solderable per MIL-STD-202, Method 208 @3:

Polarity: Cathode Band

Marking: Type Number

Ordering Information: See Page 3

Weight: 0.4 grams (approximate)

Maximum Ratings and Electrical Characteristics

@T_A = 25°C unless otherwise specified

D

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%

Characteristic		Symbol	UF 2001	UF 2002	UF 2003	UF 2004	UF 2005	UF 2006	UF 2007	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage (Note 5)		V _{RRM} V _{RWM} V _R	50	100	200	400	600	800	1000	V
RMS Reverse Voltage		V _{R(RMS)}	35	70	140	280	420	560	700	V
Average Rectified Output Current (Note 1)	@ T _A = 50°C	Io		•	·	2.0				Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on F	Rated Load	I _{FSM}				60				Α
Forward Voltage	@ I _F = 2.0A	V_{FM}		1.0		1.3		1.7		V
Peak Reverse Current at Rated DC Blocking Voltage (Note 5)	@ T _A = 25°C @ T _A = 100°C	I _{RM}				5.0 100	•			μА
Reverse Recovery Time (Note 3)		t _{rr}		5	60			75		ns
Typical Total Capacitance (Note 2)		Ст		5	60			30		pF
Typical Thermal Resistance Junction to Ambient		$R_{\theta JA}$				50	•			°C/W
Operating and Storage Temperature Range		T _{J,} T _{STG}	-65 to +150				°C			

Notes:

- 1. Valid provided that leads are maintained at ambient temperature at a distance of 9.5mm from the case.
- Measured at 1.0MHz and applied reverse voltage of 4.0V DC. Measured at $I_F = 0.5A$, $I_R = 1.0A$, $I_{rr} = 0.25A$. See figure 5.
- RoHS revision 13.2.2003. High temperature solder exemption applied, see *EU Directive Annex Note* 7.
- 5. Short duration pulse test used to minimize self heating effect.

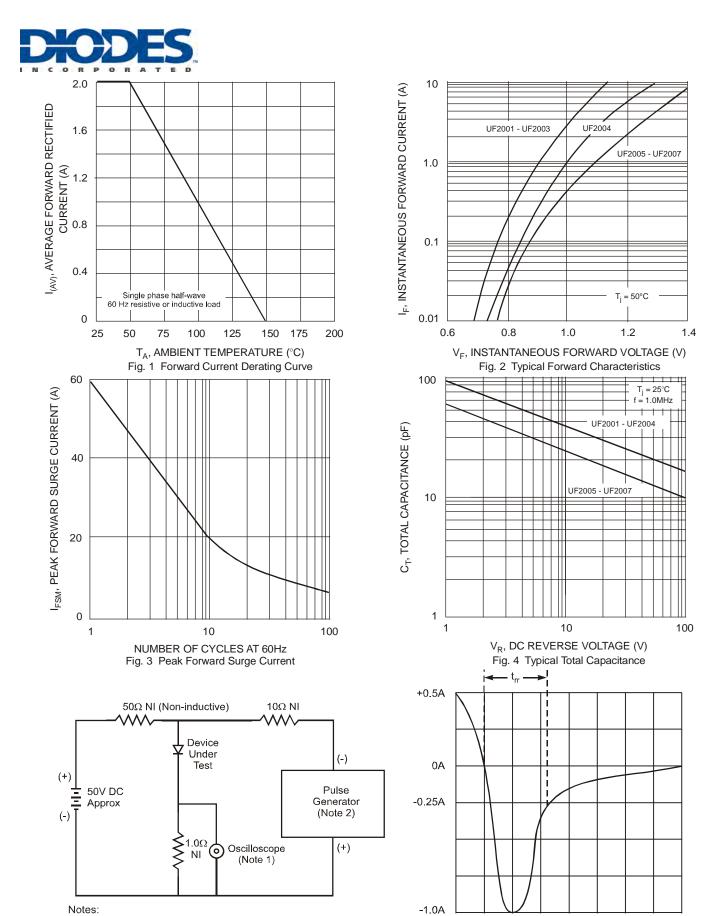


Fig. 5 Reverse Recovery Time Characteristic and Test Circuit

Set time base for 50/100 ns/cm

1. Rise Time = 7.0ns max. Input Impedance = $1.0M\Omega$, 22pF.

2. Rise Time = 10ns max. Input Impedance = 50Ω .



Ordering Information (Note 6)

Device	Packaging	Shipping		
UF2001-T	DO-15	4K/Tape & Reel, 13-inch		
UF2002-T	DO-15	4K/Tape & Reel, 13-inch		
UF2003-T	DO-15	4K/Tape & Reel, 13-inch		
UF2004-T	DO-15	4K/Tape & Reel, 13-inch		
UF2005-T	DO-15	4K/Tape & Reel, 13-inch		
UF2006-T	DO-15	4K/Tape & Reel, 13-inch		
UF2007-T	DO-15	4K/Tape & Reel, 13-inch		

6. For packaging details, visit our website at http://www.diodes.com/datasheets/ap02007.pdf.

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